

T496X336K020BH6110

T496 HRA, Tantalum, MnO₂ Tantalum, HRA, 33 uF, 10%, 20 VDC, SMD, MnO₂, Molded, Military, Fused, High Reliability, B (0.1%/1000 Hrs), 900 mOhms, 7343, 4.3 mm, 1.3 mm



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General Information

Series	T496 HRA
Dielectric	MnO ₂ Tantalum
Style	SMD Chip
Description	SMD, MnO ₂ , Molded, Military, Fused, High Reliability
Features	Internal Fuse, High Reliability
RoHS	No
Prop 65	WARNING: Cancer and reproductive harm - https://www.p65warnings.ca.gov/
SCIP Number	1dd2e1b8-26dd-4d52-927c-6f9d519011aa
Termination	Tin Lead (SnPb)
AEC-Q200	No
Typical Component Weight	652.04 mg

Dimensions

L	7.3mm +/-0.3mm
W	4mm +/-0.3mm
H	4mm +/-0.3mm
T	0.13mm REF
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm
A	3.8mm MIN
B	0.5mm +/-0.15mm
E	3.5mm REF
G	3.5mm REF
P	1.7mm REF
R	1mm REF
X	0.1mm +/-0.1mm REF

Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	500

Specifications

Capacitance	33 uF
Tolerance	10%
Voltage DC	20 VDC (85C), 13.4 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	B (0.1%/1000 Hrs)
ESR	900 mOhms (100kHz 25C)
Ripple Current	428 mA (rms, 100kHz 25C)
Leakage Current	6.6 uA (5min 25°C)
Testing and Reliability	Standard Testing Only

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